



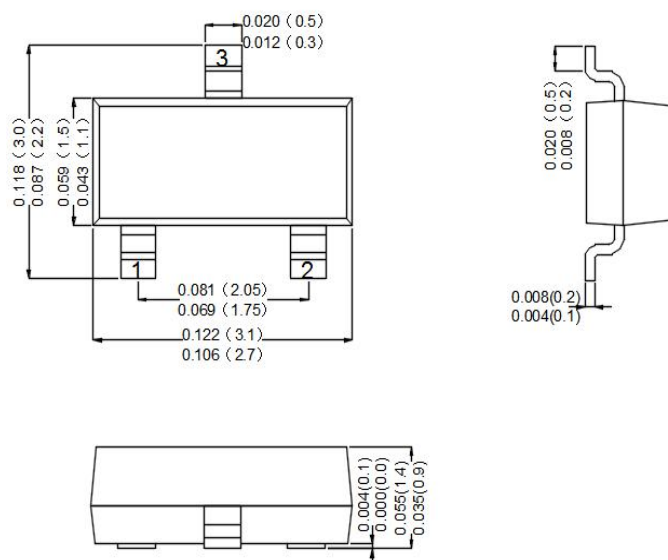
Features

- Low current (max. 100 mA)
- Low voltage (max. 32 V)
- complements:BCW61 series.

SOT-23

Mechanical Data

- Case:Molded Plastic,SOT-23
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking: BCW60B:AB ; BCW60C:AC ; BCW60D:AD
- Mounting Position : Any.
- Equivalent Circuit:



Dimensions in inches and (millimeters)

Maximum Ratings Maximum Ratings (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	32	V
Collector-Emitter Voltage	V_{CEO}	32	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	100	mA
Peak Collector Current	I_{CM}	200	mA
Peak Base Current	I_{BM}	200	mA
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_S	-65 to +150	°C

**Electrical Characteristics** (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ }\mu\text{A}$	h_{FE}	BCW60B 20	-	-	-
BCW60C 40		-	-	-	-
BCW60D 100		-	-	-	-
DC Current Gain at $V_{CE} = 5\text{ V}$, $I_C = 2\text{ mA}$		BCW60B 180	-	310	-
BCW60C 250		-	-	460	-
BCW60D 380		-	-	630	-
DC Current Gain at $V_{CE} = 1\text{ V}$, $I_C = 50\text{ mA}$		BCW60B 70	-	-	-
BCW60C 90		-	-	-	-
BCW60D 100		-	-	-	-
Collector Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$	V_{CEsat}	0.05	-	0.35	V
Collector Saturation Voltage at $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{CEsat}	0.1	-	0.55	V
Base Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$	V_{BEsat}	0.6	-	0.85	V
Base Saturation Voltage at $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{BEsat}	0.7	-	1.05	V
Base-Emitter Voltage at $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$	$V_{BE(on)}$	0.55	-	0.75	V
Collector Base Cutoff Current at $V_{CB} = 32\text{ V}$	I_{CBO}	-	-	20	nA
at $V_{CB} = 32\text{ V}$, $T_j = 150\text{ }^\circ\text{C}$		-	-	20	μA
Emitter-Base Cutoff Current at $V_{EB} = 4\text{ V}$	I_{EBO}	-	-	20	nA
Gain -Bandwidth Product at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$, $f = 100\text{ MHz}$	f_T	100	250	-	MHz
Collector-Base Capacitance at $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{CBO}	-	1.7	-	pF
Emitter-Base Capacitance at $V_{EB} = 0.5\text{ V}$, $f = 1\text{ MHz}$	C_{EBO}	-	11	-	pF
Noise figure at $I_C = 200\text{ }\mu\text{A}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ K}\Omega$, $f = 1\text{ KHz}$, $\Delta f = 200\text{ Hz}$	NF	-	2	6	dB
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	-	-	500 ¹⁾	K/W

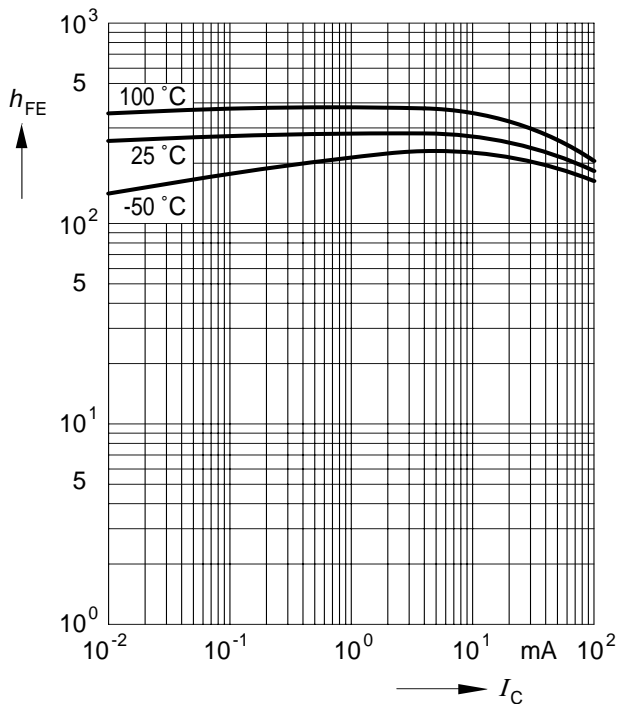
¹⁾ Transistor mounted on an FR4 printed-circuit board.



Rating And Characteristic Curves

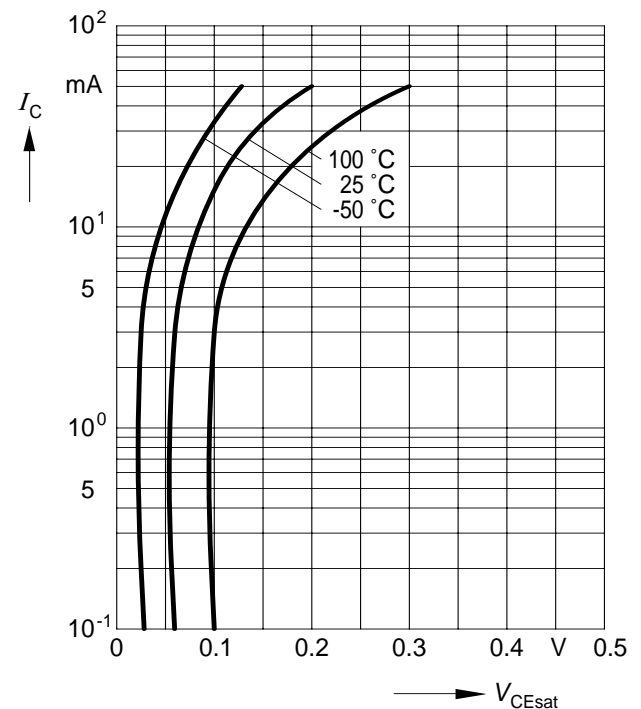
DC current gain $h_{FE} = f(I_C)$

$$V_{CE} = 5 \text{ V}$$



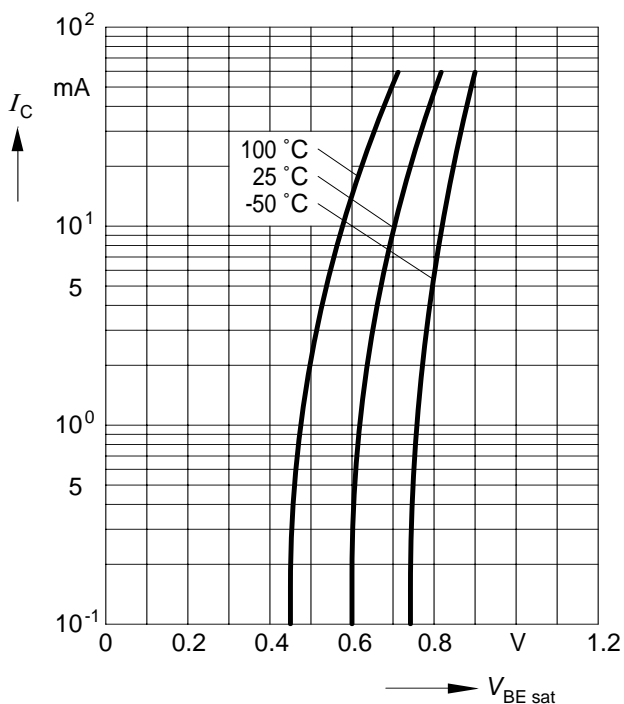
Collector-emitter saturation voltage

$$I_C = f(V_{CEsat}), h_{FE} = 10$$



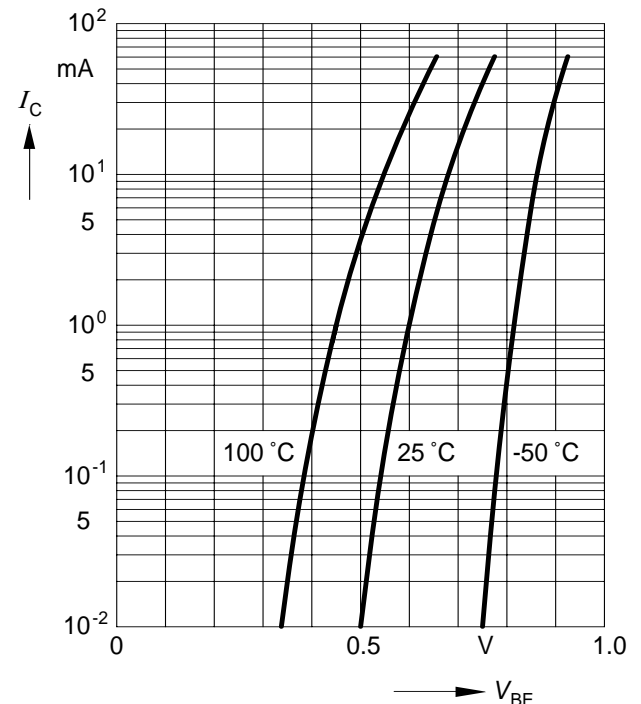
Base-emitter saturation voltage

$$I_C = f(V_{BEsat}), h_{FE} = 40$$



Collector current $I_C = f(V_{BE})$

$$V_{CE} = 5 \text{ V}$$

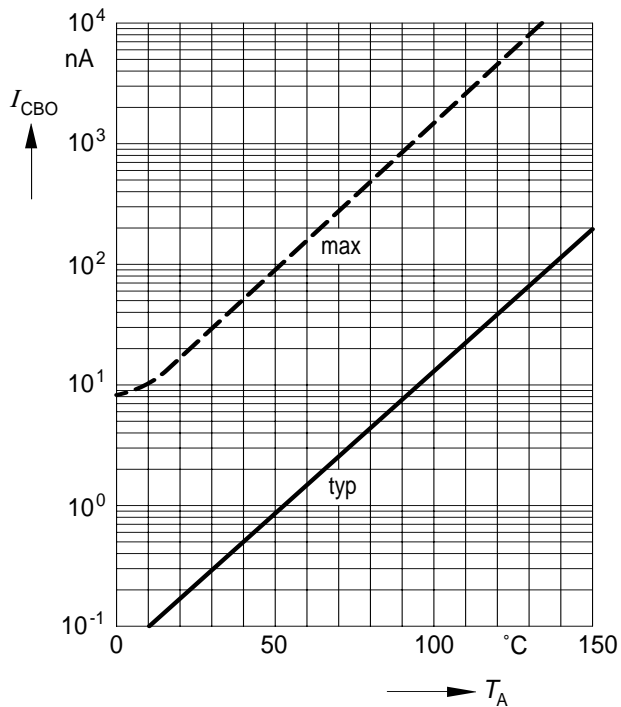




Rating And Characteristic Curves

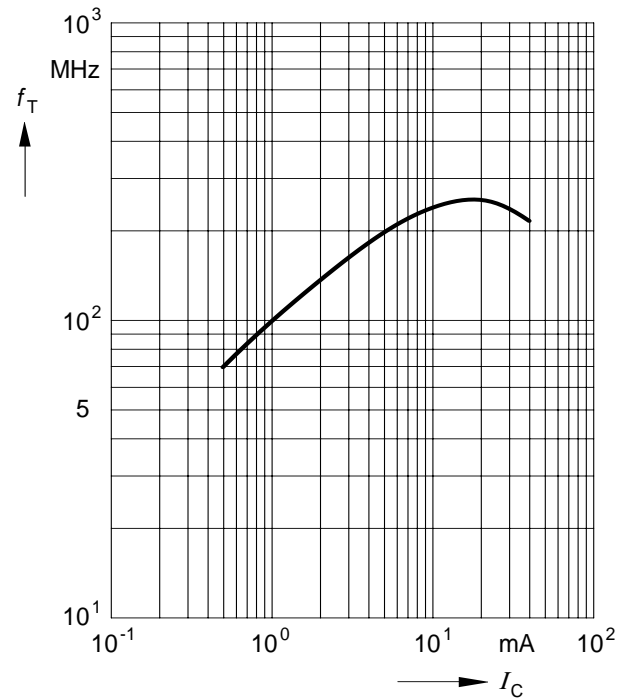
Collector cutoff current $I_{CBO} = f(T_A)$

$V_{CB} = V_{CEmax}$



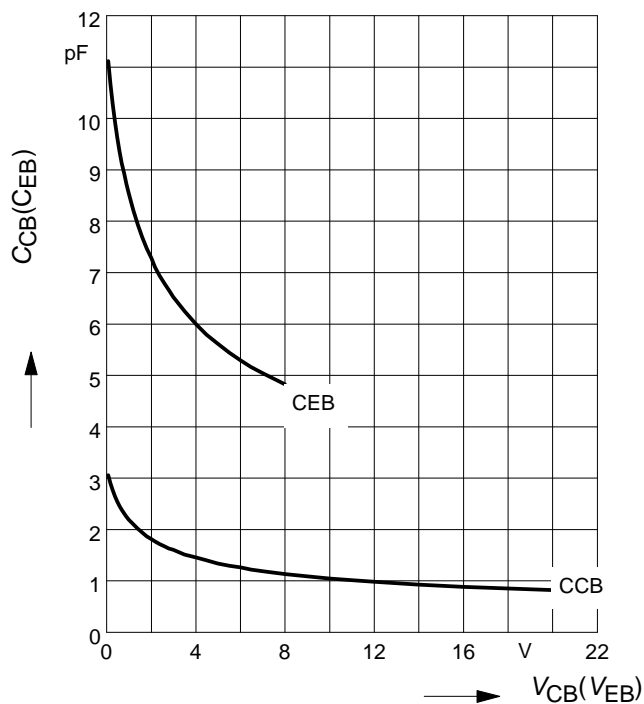
Transition frequency $f_T = f(I_C)$

$V_{CE} = \text{parameter in V, } f = 2 \text{ GHz}$

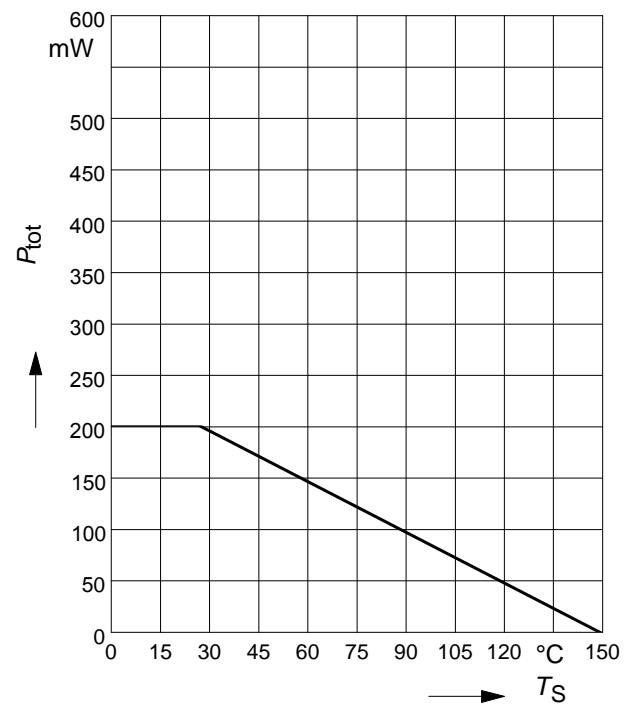


Collector-base capacitance $C_{cb} = f(V_{CB})$

Emitter-base capacitance $C_{eb} = f(V_{EB})$



Total power dissipation $P_{tot} = f(T_S)$





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